

1MBI900VXA-120PD-50

IGBT Modules

IGBT MODULE (V series) 1200V / 900A / 1 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

NPC 3-level Inverter Inverter DB for Motor Drive AC and DC Servo Drive Amplifier (DB) Active PFC Industrial machines



■ Maximum Ratings and Characteristics

■ Maximum Ratings (at T_c=25°C unless otherwise specified)

Items Collector-Emitter voltage		Symbols	Conditions		Maximum ratings	Units	
		Vces			1200	V	
Gate-Emitter voltage		V _{GES}			±20	V	
Collector current for IGBT and Inverse Diode		Ic	Continuous	Tc=25°C	1200		
			Continuous	Tc=100°C	900		
		Ic pulse	1ms		1800	Α	
		-lc			120		
		-I _{C pulse}	1ms		240		
Collector Power Dissipation		Pc	1 device		5100	W	
Reverse voltage for FWD		V _R			1200	V	
Forword current for FWD		IF	Continuous		900	Α	
		I _{F pulse}	1ms		1800	Α	
Junction temperature		Tj			175		
Operating junction temperature (under switching conditions)		Тјор			150	°C	
Case temperature		Tc			150		
Storage temperature		T _{stg}		-40 ~ +150			
Isolation voltage	between terminal and copper base (*1)	V _{iso}	AC : 1min.		4000	VAC	
	between thermistor and others (*2)	V iso			4000		
Screw Torque (*3)	Mounting	-	M5		6.0		
	Main Terminals	-	M8		10.0	Nm	
	Sense Terminals	-	M4		2.1		

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable Value : Mounting 3.0 ~ 6.0 Nm (M5)

Recommendable Value : Main Terminals 8.0 ~ 10.0 Nm (M8) Recommendable Value : Sense Terminals 1.8 ~ 2.1 Nm

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● Electrical characteristics (at T_i= 25°C unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
		Symbols			min.	typ.	max.	Offics
	Zero gate voltage collector current	Ices	V _{CE} = 1200V V _{GE} = 0V		-	-	8.0	mA
	Gate-Emitter leakage current	Iges	V _{CE} = 0V V _{GE} =±20V		-	-	1600	nA
	Gate-Emitter threshold voltage	V _{GE(th)}	V _{CE} = 20V I _C = 900mA		6.0	6.5	7.0	V
		.,		T _j = 25°C	-	1.75	2.20	
		V _{CE(sat)} (terminal) (*4)		T _j =125°C	-	2.10	-	
	Callantan Fruittan antonotian valtana	(terrillial) (4)	Ic = 900A	T _j =150°C		2.15	-	.,
GBT/Inverse Diode	Collector-Emitter saturation voltage	.,	V _{GE} =15V	T _j = 25°C	-	1.65	2.10	V
		V _{CE(sat)} (chip)		T _j =125°C	-	2.00	-	
je I		(Criip)		T _j =150°C		2.05	-	
ers	Internal gate resistance	R _G (int)	-			1.19	-	Ω
<u>≥</u>	Input capacitance	Cies	Vce=10V, Vge=0V,f=	-	83	-	nF	
31		ton	Vcc = 600V		-	1100	-	
	Turn-on time	t	Ic = 900A		-	500	-	
		t _{r (i)}	V _{GE} = ±15V		-	150	-	nsec
	Turn-off time	toff	$R_G = 1.6 \Omega$		-	1200	-	
		tı	Ls = 70nH		-	150	-	
	Forward on voltage	.,		T _j = 25°C	-	1.70	2.15	V
		V _F	I _F = 120A V _{GE} =0V	T _j =125°C	-	1.80	-	
		(terminal) (*4)		T _j =150°C		1.75	-	
				T _j = 25°C	-	1.65	2.10	
		V _F (chip)		T _j =125°C	-	1.75	-	
				T _j =150°C		1.70	-	
	Reverse Current	IR	V _{CE} = 1200V	'	-	-	8.0	mA
	Forward on voltage	.,		T _j = 25°C	-	1.70	2.15	V
		V _F (terminal) (*4)	I _F = 900A V _{GE} =0V	T _j =125°C	-	1.80	-	
FWD		(terminal) ('4)		T _j =150°C		1.75	-	
				T _j = 25°C	-	1.60	2.05	
		V _F		T _j =125°C	-	1.70	-	
		(chip)		T _j =150°C		1.65	-	
	Reverse recovery time	trr	I _F = 900A	<u>'</u>	-	200	-	nsec
tor	B. et at a cons	Ь	T = 25°C		-	5000	-	Ω
Thermistor	Resistance	R	T = 100°C		465	495	520	
The	value B T = 25/50°C		3305	3375	3450	K		

Note *4: Please refer to page 8, there is definition of on-state voltage at terminal.

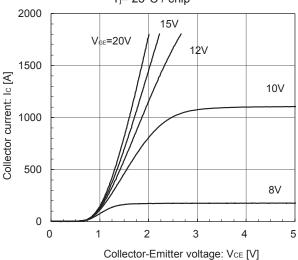
● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items		Conditions	min.	typ.	max.	Ullits
		Inverter IGBT	-	-	0.030	°C/W
Thermal resistance (1device)	R _{th(j-c)}	Inverse Diode	-	-	0.340	
		FWD	-	-	0.036	
Contact thermal resistance (1device) (*5) R _{th(c-f)}		with Thermal Compound	-	0.00625	-	

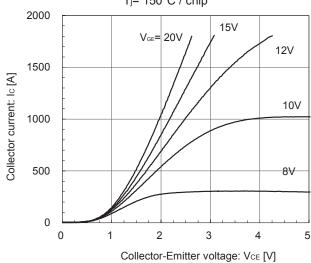
Note *5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

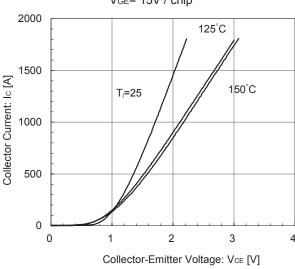




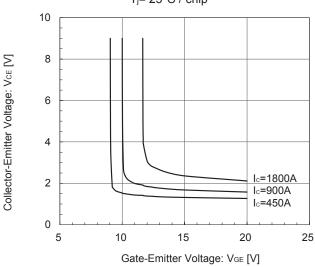
Collector current vs. Collector-Emitter voltage (typ.) T_j = 150°C / chip



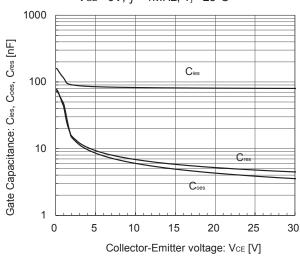
Collector current vs. Collector-Emitter voltage (typ.) V_{GE} = 15V / chip



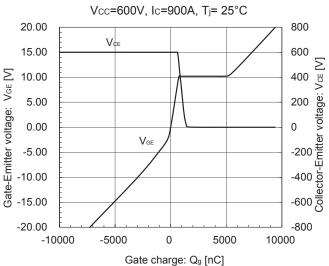
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) $T_j=25^{\circ}\text{C}$ / chip

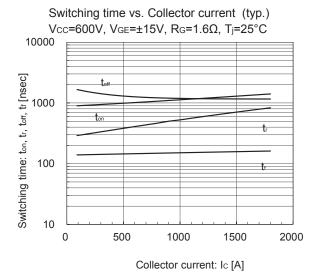


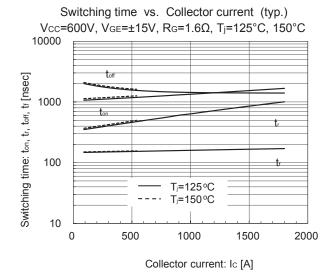
Gate Capacitance vs. Collector-Emitter Voltage (typ.) $V_{GE} = 0V, f = 1MHz, T_i = 25$ °C

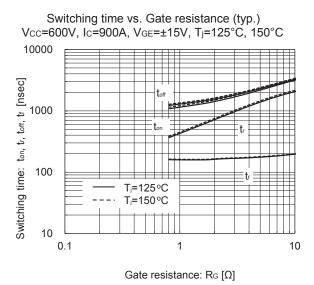


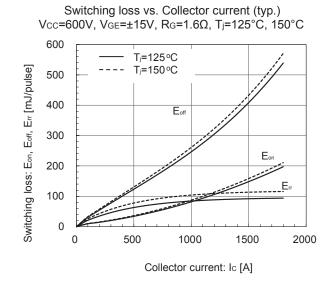
Dynamic Gate Charge (typ.)

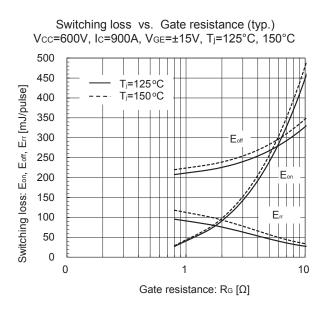


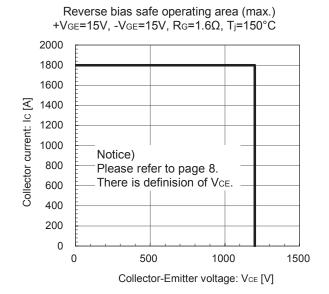


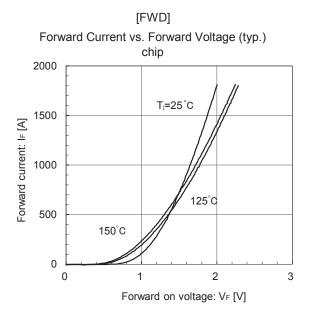






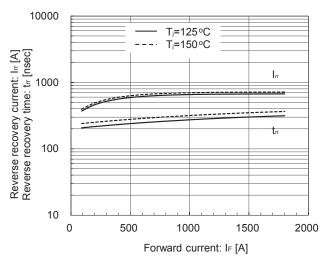




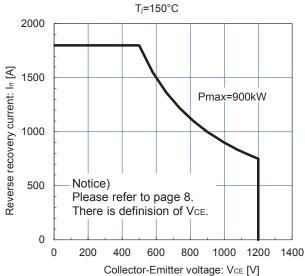


Reverse Recovery Characteristics (typ.) $V_{CC}=600V$, $V_{GE}=\pm15V$, $R_{G}=1.6\Omega$, $T_{I}=125^{\circ}C$, $150^{\circ}C$

[FWD]



[FWD]
FWD safe operating area (max.)



Reverse Recovery Characteristics (typ.)

Vcc=600V, V_{GE}=±15V, R_G=1.6Ω, T_j=25°C

10000

t_π

1000

t_π

100

10

[Inverse Diode]
Forward Current vs. Forward Voltage (typ.)
chip

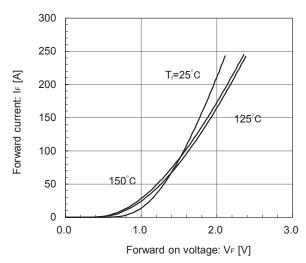
1000

Forward current: IF [A]

1500

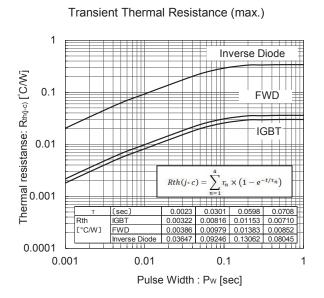
2000

500



100 120 140 160

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Temperature characteristic (typ.)

Temperature [°C]

[THERMISTOR]

100

10

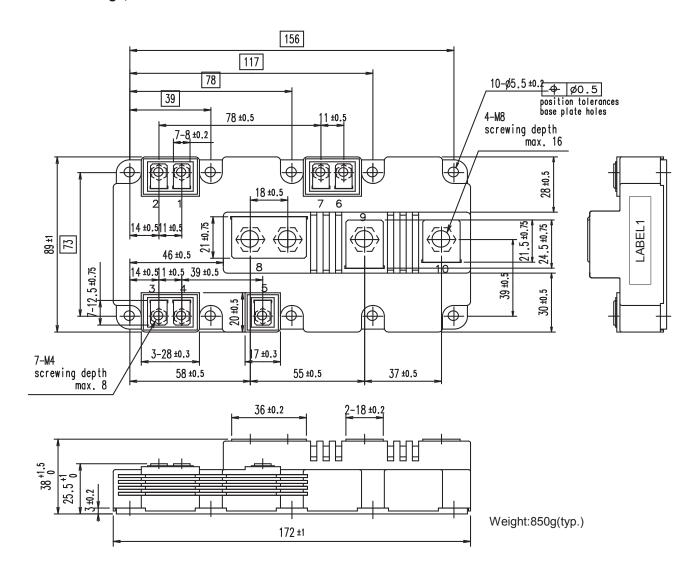
0.1

-40 -20

0 20 40 60 80

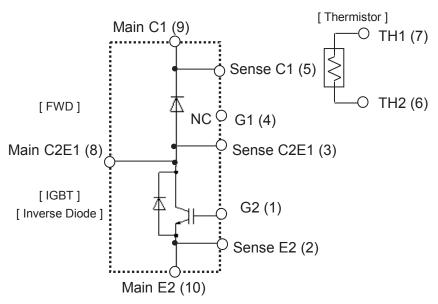
Resistance : R [kΩ]

■ Outline Drawings, mm



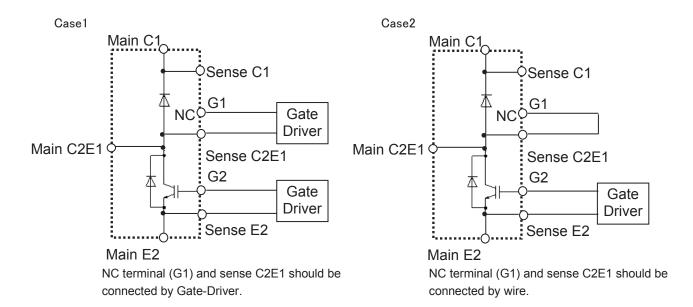
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■ Equivalent Circuit Schematic

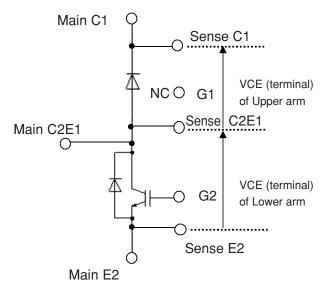


Notice) There is recommendation of wiring for NC terminal as follows

■ Fuji recommends wire connection of CASE1 or CASE2 to fix NC terminal voltage.



■ Definition of on-state voltage at terminal and switching characteristics



Fuji defined VCE value of terminal by using Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm.

Switching characteristics of VCE also is defined between Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm.

Please use these terminals whenever measure spike voltage and on-state voltage .

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IGBT Modules

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